

L Number	Hits	Search Text	DB	Time stamp
1	561083	(plasma near3 chamber) chamber	USPAT; US-PGPUB	2003/05/21 13:28
2	141200	((plasma near3 chamber) chamber) and (bias voltage)	USPAT; US-PGPUB	2003/05/21 13:31
3	80045	((plasma near3 chamber) chamber) and (bias voltage)) and current	USPAT; US-PGPUB	2003/05/21 13:32
4	27754	((((plasma near3 chamber) chamber) and (bias voltage)) and current) and monitor\$3	USPAT; US-PGPUB	2003/05/21 13:33
5	26368	(((((plasma near3 chamber) chamber) and (bias voltage)) and current) and monitor\$3) and control\$4	USPAT; US-PGPUB	2003/05/21 13:34
6	20520	(((((plasma near3 chamber) chamber) and (bias voltage)) and current) and monitor\$3) and control\$4) and power	USPAT; US-PGPUB	2003/05/21 13:35
7	1871	((((((plasma near3 chamber) chamber) and (bias voltage)) and current) and monitor\$3) and control\$4) and power) and ((wafer substrate) near5 (hold\$3 Pedestal))	USPAT; US-PGPUB	2003/05/21 14:10
9	0	("7 and (ground near3 current)").PN.	USPAT; US-PGPUB	2003/05/21 14:56
10	51	((((((((plasma near3 chamber) chamber) and (bias voltage)) and current) and monitor\$3) and control\$4) and power) and ((wafer substrate) near5 (hold\$3 Pedestal))) and (ground near3 current)	USPAT; US-PGPUB	2003/05/21 14:56